Nanoscale polarization relaxation in a polycrystalline ferroelectric thin film: Role of local environments

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In this letter, we report on the study of nanoscale polarization relaxation phenomena in polycrystalline PbZr0.4Ti0.6O3 films. Piezoresponse force microscopy (PFM) images of the as-grown sample reveal grains with a range of contrast, from fully white to gray to fully black. It is shown that this local change in the contrast (magnitude) of the piezoresponse from grain to grain can be attributed to the crystallographic orientation within each grain. PFM-based relaxation experiments show that the rate of relaxation is different for each grain, furthermore it is strongly dependent on the tilt of individual crystallographic orientation with respect to the polar axis. Strongly tilted away nonpolar axis grains show a much stronger decay of the polarization compared to polar axis-oriented grains. Therefore, for an ensemble of grains under a common top electrode, the relaxation events would first take place in grains, which are nonpolar axis oriented. © 2005 American Institute of Physics. [DOI: 10.1063/1.1977183]

The properties of ferroelectric materials at the nanoscale have attracted considerable attention over the past few years. Of equal importance is the ability to measure and characterize ferroelectric devices at the nanoscale and hence electrical characterization with scanned probe microscopy, especially piezoresponse force microscopy (PFM), has tremendously progressed. This technique has been used in an exhaustive manner to understand nanoscale ferroelectric domain structure, polarization relaxation, domain-wall creep, piezoelectric properties, reliability issues, and properties of individual grains.

Although there are reports that correlate piezoresponse of the ferroelectric thin film to the possible crystallographic orientation within each grain, PFM-based relaxation experiments show that the rate of relaxation is different for each grain, furthermore it is strongly dependent on the tilt of individual crystallographic orientation with respect to the polar axis. Strongly tilted away nonpolar axis grains show a much stronger decay of the polarization compared to polar axis-oriented grains. Therefore, for an ensemble of grains under a common top electrode, the relaxation events would first take place in grains, which are nonpolar axis oriented. © 2005 American Institute of Physics. [DOI: 10.1063/1.1977183]

\[ d_{zz}(\theta) = (d_{31} + d_{33}) \sin^2 \theta \cos \theta + d_{33} \cos^3 \theta. \] (1)

Equation (1) shows that \( d_{zz} \) would be maximum for those grains oriented along the (001) orientation (i.e., with an angle \( \theta = 0^\circ \) or \( 180^\circ \)), equal to the \( d_{33} \), and for all other orientations, the magnitude of \( d_{zz} \) (and, hence, the piezoresponse contrast) would be dependent on \( \theta \). Figure 1(b) is a typical vertical PFM (VPFM) image of the ferroelectric film. It shows a number of grains, each about 50–100 nm in size. We immediately observe a wide range of contrast in the grain; from fully white (Grain A) to gray (Grain B) to fully black (Grain C). We did not observe any 90° domain twins within each grain, unlike the scenario in PbTiO3 films. From the phase image acquired concurrent with the VPFM, we do not observe any 180°-type phase boundaries within regions of the same contrast, unlike those reported by Stolichnov.
and Gruverman et al.\textsuperscript{7} We thus conclude that the difference in the magnitude (and hence contrast) in the piezoresponse between the individual grains is due to different crystallographic orientations. The piezoresponse of Grains A and C in the VPFM image was maximum, and zero in the lateral PFM graphic orientations. The piezoresponse of Grains A and C in between the individual grains is due to different crystallographic orientations. For a full 3D plot refer to Uchino function of the angle made by the crystallographic orientation with the polar axis of the grains show gray contrast in the magnitude of the applied voltage of $-4\ V$. Figure 2 is a series of VPFM images of a region after writing a submicron bit with an SBT film by Kalinin\textsuperscript{25} and Gruverman\textsuperscript{7}.

To understand the impact of such various grain orientations on the polarization relaxation, we performed PFM-based relaxation experiments. Figure 2 is a series of VPFM images of a region after writing a submicron bit with an applied voltage of $-4\ V$. Figure 2(a) is an image of the virgin surface; Fig. 2(b) is a scan of the central region with the bit in the “as-written” state. After an application of dc bias, the contrast is changed to black, in comparison to a lighter unaffected background. Figures 2(c)–2(f) are images taken after several time intervals, from 512 s to 97 000 s. In order to eliminate tip wear-induced effects and ensure a rigorous calibration, a marker grain was chosen which was significantly away from the poled region, and thus not affected by the applied voltage. For each image, the piezoresponse was calibrated with respect to this marker grain. A primary observation is that, unlike our previous report on epitaxial PZT films,\textsuperscript{11} no significant lateral shrinkage of the written bit is observed.

In contrast, for grains within the written bit, a monotonic decrease in the reduction of the vertical piezoresponse signal was observed as a function of time, indicating vertical back switching similar to previously published reports by other groups.\textsuperscript{12,29} Figure 3(a) shows the piezoresponse measured as a function of time for four grains—Black (B), White (W), Gray-1 (G1), and Gray-2 (G2), from Fig. 2. Each of the grains were approximately 50–100 nm in size. In order to plot them on the same scale, the piezoresponse was normalized with respect to the original piezoresponse for each individual grain. The solid lines in each plot are fits to a stretch exponential of the form:

$$P = P_{0}\ exp\left(-\frac{t}{\tau}\right)^{n}$$  \hspace{1cm} (2)

where $n$ is the dimensional constant and $\tau$ is the characteristic time. The grain which was fully black or fully white in the “as-written” state. After an application of dc bias, the polarization is oriented fully in plane, i.e., along (010) or (100) orientation. On the other hand, majority of the grains show gray contrast (hereafter referred to as gray grains) in both, the VPFM and LPFM response, with the intensity ranging from 50 to 65% of the maximum (for e.g., Grain B). These grains have their polarization vector at an angle with the film normal. Figure 1 shows a piezoreponse loop measured for a fully white grain and a typical gray grain. We see that the maximum response for the white grain similar to studies on SBT films,\textsuperscript{25} where gray grains (nonpolar axis oriented) show a lower piezoresponse than the white grains. In addition, the coercive voltage for the gray grain is significantly larger than that of the white grain similar to studies on SBT films by Kalinin et al.\textsuperscript{25}

![FIG. 1. (Color online) (a) Effective out-of-plane piezoresponse, $d_{33}$, as a function of the angle made by the crystallographic orientation with the polarization vector. For a full 3D plot refer to Uchino et al. (Ref. 26) and Haratse et al. (Ref. 27). (b) Typical VPFM image of the PZT film used in this study. Three grains are marked, fully white (A), gray (B) and fully black (C). (c) Piezoresponse loops for Grains A (open squares) and B (solid triangles).](image-url)
the original state, shows only marginal relaxation with the signal dropping by less than 5%. We note that for both grains the exponent is constant, $n$ to be $\sim 0.25$ although $\tau$ for the black grain ($\sim 5 \times 10^3$ s) was significantly larger compared to the white grain ($\sim 3.25 \times 10^3$ s). On the other hand, the relaxation behaviors of grains that were originally gray in contrast are markedly different. These grains in general relax much quicker than the fully black or fully white grains. Although the value of $n (= 0.25)$ was not different from the (001) grains, the time constants were markedly worse, with $\tau$ dropping to only $10^3$ s. Since these grains form a majority of the film, it is hence not surprising that they would dominate the relaxation process for an ensemble of grains. In Fig. 3(b), we plot the characteristic time, $\tau$, measured for the $-4$ V write experiment plotted as a function of the angle of deviation $[\cos(\theta)]$ for many grains. The line is a guide for the eyes. For grains whose polar axis are (001) or (001) oriented (at the opposite ends of the $x$ axis), $\tau$ is very high. As one deviates further away from the polar axis, i.e., moves toward lower $\cos(\theta)$, $\tau$ changes from $10^3$ s to only $10^1$ s. Thus, a systematic drop in $\tau$ is observed, commensurate with the angle of deviation $\theta$.

An explanation of the observed accelerated polarization relaxation in the nonpolar grains could be that the effective switching field is lower than that compared for polar axis grains. This can be deduced from the $d_{33}$ loops in Fig. 1(a), where in the polar axis Grain A has a much lower coercive voltage compared to the nonpolar axis Grain B. Figure 4(a) plots the polarization relaxation dependence for typical gray grains as a function of three write voltages: $-2$ V, $-4$ V, and $8$ V. As $-2$ V is below the coercive voltage the grain relaxes much faster. However, the time dependent behavior for the $-4$ and $-8$ V are very similar. It can be concluded that the observed phenomena cannot be explained because of a lower switching field—although this may play a role in the complete picture.

In order to understand this preferential backswitching shown by the nonpolar grains, we must look at the electrostatics of the domain reversal process. Figure 4 is a three-dimensional (3D) sketch of the polarization derived from a typical PFM image. It shows that for fully black or white grains, there is no polarization charge across the grain boundary and hence the $\text{div } P = 0$. However, for nonpolar axis-oriented grains, the polarization makes finite angles with the neighboring grains creating a nonzero charge at the grain boundary. This would create a strong depoling field at these interfaces, which has its source at the divergence of the polarization across the grain boundary. It is obvious that the stronger the deviation of the polarization across the grain boundary, the stronger the depolarization field. Thus, larger values of $\theta$, would lead to larger divergence at this interface and, consequently, a larger depolarizing field. This depolarizing field would favor the immediate nucleation of reverse domains.\textsuperscript{13,30}

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